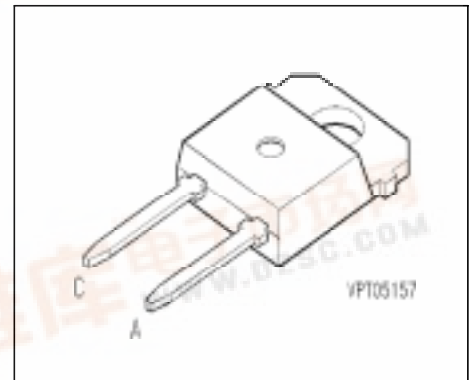


FRED Diode

- Fast recovery epitaxial diode
- Soft recovery characteristics



| Type | V_{RRM} | I_{FRMS} | t_{rr} | Package | Ordering Code |
|---------|-----------|------------|----------|-----------|-----------------|
| BYP 103 | 1000V | 75A | 140ns | TO-218 AD | C67047-A2066-A2 |

Maximum Ratings

| Parameter | Symbol | Values | Unit |
|--------------------------------------------------------------------------------------------------------|---------------|---------------|------------------|
| Mean forward current $T_C = 90\text{ }^\circ\text{C}, D = 0.5$ | I_{FAV} | 45 | A |
| RMS forward current | I_{FRMS} | 75 | |
| Surge forward current, sine halfwave, aperiodic $T_j = 100\text{ }^\circ\text{C}, f = 50\text{ Hz}$ | I_{FSM} | 180 | |
| Repetitive peak forward current $T_j = 100\text{ }^\circ\text{C}, t_p \leq 10\text{ }\mu\text{s}$ | I_{FRM} | 400 | |
| i^2t value $T_j = 100\text{ }^\circ\text{C}, t_p = 10\text{ ms}$ | $\int I^2 dt$ | 162 | A ² s |
| Repetitive peak reverse voltage | V_{RRM} | 1000 | V |
| Surge peak reverse voltage | V_{RSM} | 1000 | |
| Power dissipation $T_C = 90\text{ }^\circ\text{C}$ | P_{tot} | 115 | W |
| Chip or operating temperature | T_j | -40 ... + 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -40 ... + 150 | |
| Thermal resistance, chip case | R_{thJC} | ≤ 0.5 | K/W |
| Thermal resistance, chip-ambient | R_{thJA} | ≤ 46 | |
| DIN humidity category, DIN 40 040 | - | E | - |
| IEC climatic category, DIN IEC 68-1 | - | 40 / 150 / 56 | |

Electrical Characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|-----------|--------|--------|------|------|------|
| | | min. | typ. | max. | |

Static Characteristics

| | | | | | |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|---|--------------------------|----------------|----|
| Forward voltage drop $I_F = 30\text{ A}$, $T_j = 25\text{ °C}$ $I_F = 45\text{ A}$, $T_j = 25\text{ °C}$ $I_F = 30\text{ A}$, $T_j = 100\text{ °C}$ $I_F = 45\text{ A}$, $T_j = 100\text{ °C}$ | V_F | - | 1.7 1.9 1.3 1.5 | - 2.35 - | V |
| Reverse current $V_R = 1000\text{ V}$, $T_j = 25\text{ °C}$ $V_R = 1000\text{ V}$, $T_j = 100\text{ °C}$ $V_R = 1000\text{ V}$, $T_j = 150\text{ °C}$ | I_R | - | 0.01 0.05 0.15 | 0.25 - | mA |

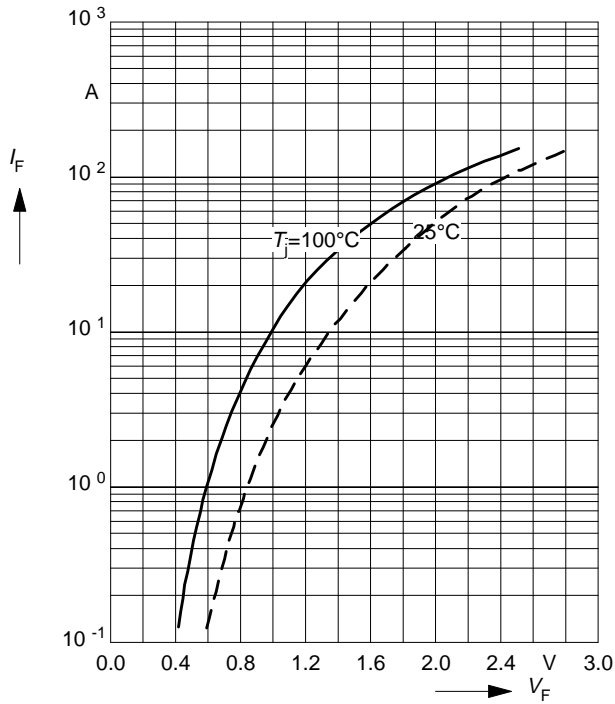
AC Characteristics

| | | | | | |
|--------------------------------------------------------------------------------------------------------------------------------------------------|-----------|---|-----|---|---------------|
| Reverse recovery charge $I_F = 45\text{ A}$, $V_{CC} = 300\text{ V}$, $di_F/dt = -1000\text{ A}/\mu\text{s}$ $T_j = 100\text{ °C}$ | Q_{rr} | - | 6 | - | μC |
| Peak reverse recovery current $I_F = 45\text{ A}$, $V_{CC} = 300\text{ V}$, $di_F/dt = -1000\text{ A}/\mu\text{s}$ $T_j = 100\text{ °C}$ | I_{RRM} | - | 60 | - | A |
| Reverse recovery time $I_F = 45\text{ A}$, $V_{CC} = 300\text{ V}$, $di_F/dt = -1000\text{ A}/\mu\text{s}$ $T_j = 100\text{ °C}$ | t_{rr} | - | 140 | - | ns |
| Storage time $I_F = 45\text{ A}$, $V_{CC} = 300\text{ V}$, $di_F/dt = -1000\text{ A}/\mu\text{s}$ $T_j = 100\text{ °C}$ | t_S | - | 70 | - | |
| Softfaktor $I_F = 45\text{ A}$, $V_{CC} = 300\text{ V}$, $di_F/dt = -1000\text{ A}/\mu\text{s}$ $T_j = 100\text{ °C}$ | S | - | 1 | - | - |

Typ. forward characteristics

$$I_F = f(V_F)$$

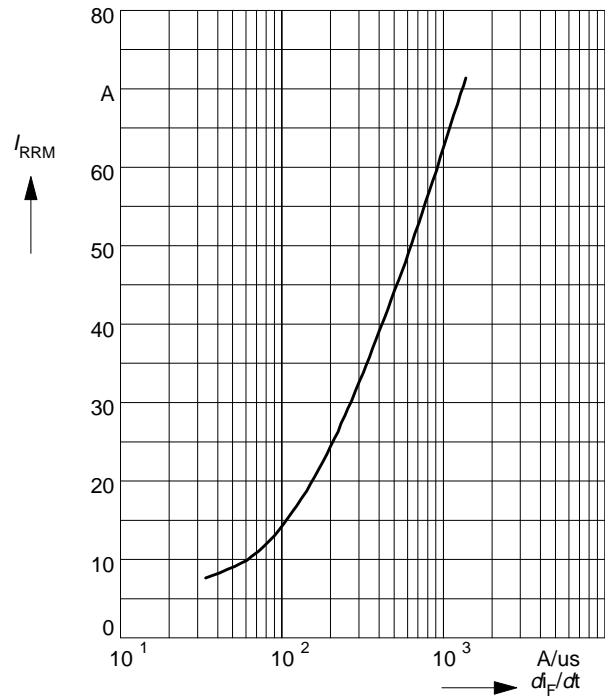
parameter: T_j



Typ. reverse current

$$I_{RRM} = f(dI_F / dt)$$

parameter: $V_{CC} = 300\text{ V}, I_F = 45\text{ A}, T_j = 100^\circ\text{C}$



Typ. reverse recovery charge

$$Q_{rr} = f(dI_F / dt)$$

parameter: $V_{CC} = 300\text{ V}, I_F = 45\text{ A}, T_j = 100^\circ\text{C}$

